
Oral presentation | 15 Crystal Engineering | 15.4 III-V-group nitride crystals

[12p-W541-1~12]15.4 III-V-group nitride crystals

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Tue. Mar 12, 2019 1:30 PM - 5:00 PM W541 (W541)

△ : Presentation by Applicant for JSAP Young Scientists Presentation Award

▲ : English Presentation

▼ : Both of Above

No Mark : None of Above

1:30 PM - 2:00 PM

[12p-W541-1][INVITED] Development of hetero-epitaxial growth techniques of Al-based nitride semiconductors and deep-UV LEDs using them

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Keywords:Al-based nitride semiconductors, hetero epitaxial growth technologies, deep-UV LEDs